

MC34167, MC33167

Inverting Switching Regulators - Step-Up/Down

5.0 A

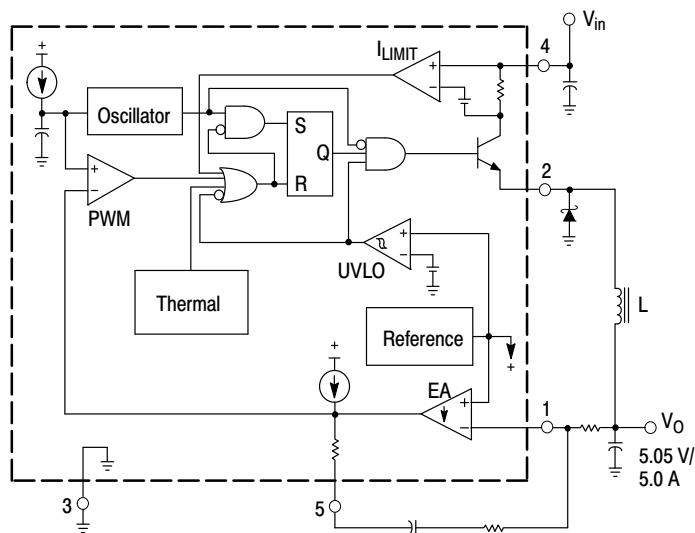
The MC34167, MC33167 series are high performance fixed frequency power switching regulators that contain the primary functions required for dc-to-dc converters. This series was specifically designed to be incorporated in step-down and voltage-inverting configurations with a minimum number of external components and can also be used cost effectively in step-up applications.

These devices consist of an internal temperature compensated reference, fixed frequency oscillator with on-chip timing components, latching pulse width modulator for single pulse metering, high gain error amplifier, and a high current output switch.

Protective features consist of cycle-by-cycle current limiting, undervoltage lockout, and thermal shutdown. Also included is a low power standby mode that reduces power supply current to 36 μ A.

Features

- Output Switch Current in Excess of 5.0 A
- Fixed Frequency Oscillator (72 kHz) with On-Chip Timing
- Provides 5.05 V Output without External Resistor Divider
- Precision 2% Reference
- 0% to 95% Output Duty Cycle
- Cycle-by-Cycle Current Limiting
- Undervoltage Lockout with Hysteresis
- Internal Thermal Shutdown
- Operation from 7.5 V to 40 V
- Standby Mode Reduces Power Supply Current to 36 μ A
- Economical 5-Lead TO-220 Package with Two Optional Leadforms
- Also Available in Surface Mount D²PAK Package
- Moisture Sensitivity Level (MSL) Equals 1
- Pb-Free Packages are Available



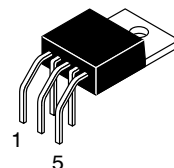
This device contains 143 active transistors.
Figure 1. Simplified Block Diagram
(Step Down Application)



ON Semiconductor®

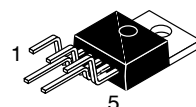
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MARKING DIAGRAMS

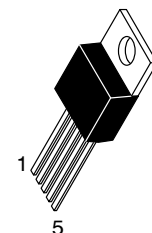


**TO-220
TH SUFFIX
CASE 314A**

Heatsink surface connected to Pin 3

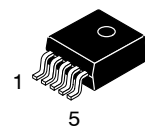


**TO-220
TV SUFFIX
CASE 314B**



**TO-220
T SUFFIX
CASE 314D**

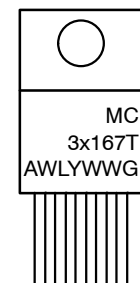
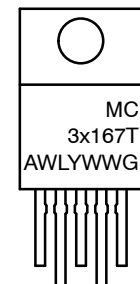
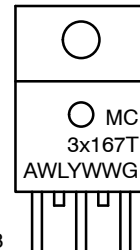
- Pin
1. Voltage Feedback Input
 2. Switch Output
 3. Ground
 4. Input Voltage/ V_{CC}
 5. Compensation/Standby



**D²PAK
D2T SUFFIX
CASE 936A**

Heatsink surface (shown as terminal 6 in case outline drawing) is connected to Pin 3

- x = 3 or 4
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 17 of this data sheet.

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MAXIMUM RATINGS (Note 1 and 2)

Rating	Symbol	Value	Unit
Power Supply Input Voltage	V _{CC}	40	V
Switch Output Voltage Range	V _{O(switch)}	−2.0 to + V _{in}	V
Voltage Feedback and Compensation Input Voltage Range	V _{FB} , V _{Comp}	−1.0 to + 7.0	V
Power Dissipation			
Case 314A, 314B and 314D (T _A = +25°C)	P _D	Internally Limited	W
Thermal Resistance, Junction-to-Ambient	θ _{JA}	65	°C/W
Thermal Resistance, Junction-to-Case	θ _{JC}	5.0	°C/W
Case 936A (D ² PAK) (T _A = +25°C)	P _D	Internally Limited	W
Thermal Resistance, Junction-to-Ambient	θ _{JA}	70	°C/W
Thermal Resistance, Junction-to-Case	θ _{JC}	5.0	°C/W
Operating Junction Temperature	T _J	+150	°C
Operating Ambient Temperature (Note 3)	T _A		°C
MC34167		0 to + 70	
MC33167		− 40 to + 85	
Storage Temperature Range	T _{stg}	− 65 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- Maximum package power dissipation limits must be observed to prevent thermal shutdown activation.
- This device series contains ESD protection and exceeds the following tests:
Human Body Model 2000 V per MIL-STD-883, Method 3015.
Machine Model Method 200 V.
- | | |
|---|--|
| $T_{low} = 0^{\circ}\text{C}$ for MC34167 | $T_{high} = +70^{\circ}\text{C}$ for MC34167 |
| $= -40^{\circ}\text{C}$ for MC33167 | $= +85^{\circ}\text{C}$ for MC33167 |

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ELECTRICAL CHARACTERISTICS ($V_{CC} = 12\text{ V}$, for typical values $T_A = +25^\circ\text{C}$, for min/max values T_A is the operating ambient temperature range that applies (Notes 4, 5), unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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OSCILLATOR

Frequency ($V_{CC} = 7.5\text{ V to } 40\text{ V}$)	$T_A = +25^\circ\text{C}$ $T_A = T_{\text{low}} \text{ to } T_{\text{high}}$	f_{OSC}	65 62	72 –	79 81	kHz
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ERROR AMPLIFIER

Voltage Feedback Input Threshold	$T_A = +25^\circ\text{C}$ $T_A = T_{\text{low}} \text{ to } T_{\text{high}}$	$V_{\text{FB(th)}}$	4.95 4.85	5.05 –	5.15 5.20	V
Line Regulation ($V_{CC} = 7.5\text{ V to } 40\text{ V}$, $T_A = +25^\circ\text{C}$)		Reg_{line}	–	0.03	0.078	%/V
Input Bias Current ($V_{\text{FB}} = V_{\text{FB(th)}} + 0.15\text{ V}$)		I_{IB}	–	0.15	1.0	μA
Power Supply Rejection Ratio ($V_{CC} = 10\text{ V to } 20\text{ V}$, $f = 120\text{ Hz}$)		PSRR	60	80	–	dB
Output Voltage Swing	High State ($I_{\text{Source}} = 75\text{ }\mu\text{A}$, $V_{\text{FB}} = 4.5\text{ V}$) Low State ($I_{\text{Sink}} = 0.4\text{ mA}$, $V_{\text{FB}} = 5.5\text{ V}$)	V_{OH} V_{OL}	4.2 –	4.9 1.6	– 1.9	V

PWM COMPARATOR

Duty Cycle ($V_{CC} = 20\text{ V}$)	Maximum ($V_{\text{FB}} = 0\text{ V}$) Minimum ($V_{\text{Comp}} = 1.9\text{ V}$)	$\text{DC}_{(\text{max})}$ $\text{DC}_{(\text{min})}$	92 0	95 0	100 0	%
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SWITCH OUTPUT

Output Voltage Source Saturation ($V_{CC} = 7.5\text{ V}$, $I_{\text{Source}} = 5.0\text{ A}$)	V_{sat}	–	($V_{CC} - 1.5$)	($V_{CC} - 1.8$)	V
Off-State Leakage ($V_{CC} = 40\text{ V}$, Pin 2 = GND)	$I_{\text{sw(off)}}$	–	0	100	μA
Current Limit Threshold ($V_{CC} = 7.5\text{ V}$)	$I_{\text{pk(switch)}}$	5.5	6.5	8.0	A
Switching Times ($V_{CC} = 40\text{ V}$, $I_{\text{pk}} = 5.0\text{ A}$, $L = 225\text{ }\mu\text{H}$, $T_A = +25^\circ\text{C}$)	t_r t_f	– –	100 50	200 100	ns

UNDERVOLTAGE LOCKOUT

Startup Threshold (V_{CC} Increasing, $T_A = +25^\circ\text{C}$)	$V_{\text{th(UVLO)}}$	5.5	5.9	6.3	V
Hysteresis (V_{CC} Decreasing, $T_A = +25^\circ\text{C}$)	$V_{\text{H(UVLO)}}$	0.6	0.9	1.2	V

TOTAL DEVICE

Power Supply Current ($T_A = +25^\circ\text{C}$)	I_{CC}	–	36	100	μA
Standby ($V_{CC} = 12\text{ V}$, $V_{\text{Comp}} < 0.15\text{ V}$)		–	40	60	mA
Operating ($V_{CC} = 40\text{ V}$, Pin 1 = GND for maximum duty cycle)		–			

4. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
 5. $T_{\text{low}} = 0^\circ\text{C}$ for MC34167 $T_{\text{high}} = +70^\circ\text{C}$ for MC34167
 $= -40^\circ\text{C}$ for MC33167 $= +85^\circ\text{C}$ for MC33167

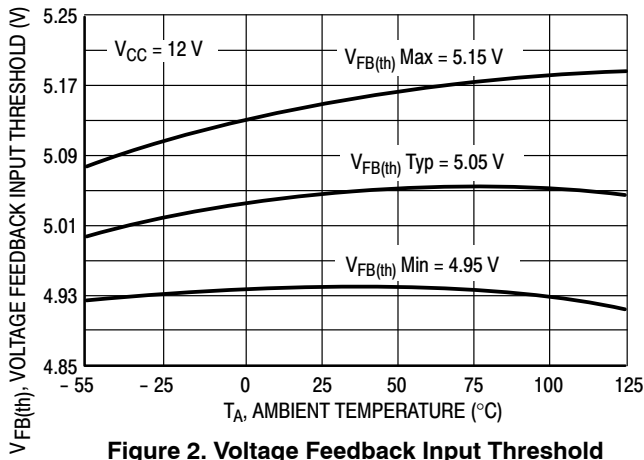


Figure 2. Voltage Feedback Input Threshold versus Temperature

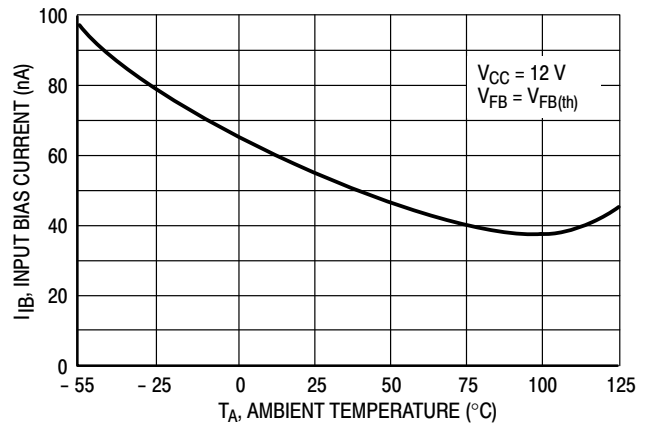


Figure 3. Voltage Feedback Input Bias Current versus Temperature

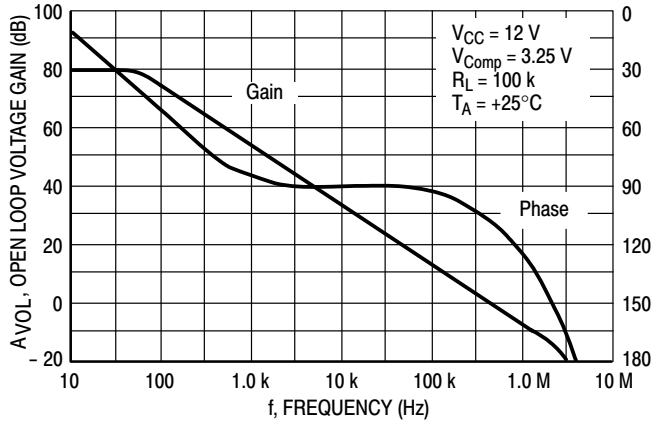


Figure 4. Error Amp Open Loop Gain and Phase versus Frequency

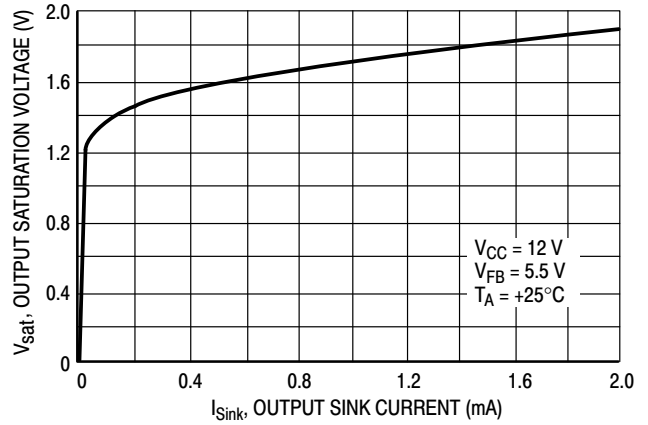


Figure 5. Error Amp Output Saturation versus Sink Current

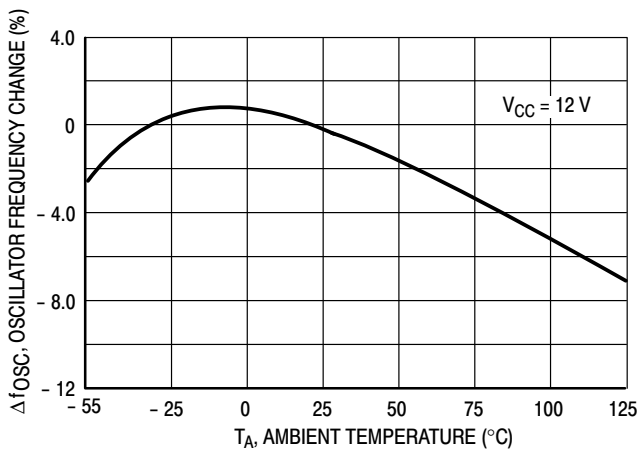


Figure 6. Oscillator Frequency Change versus Temperature

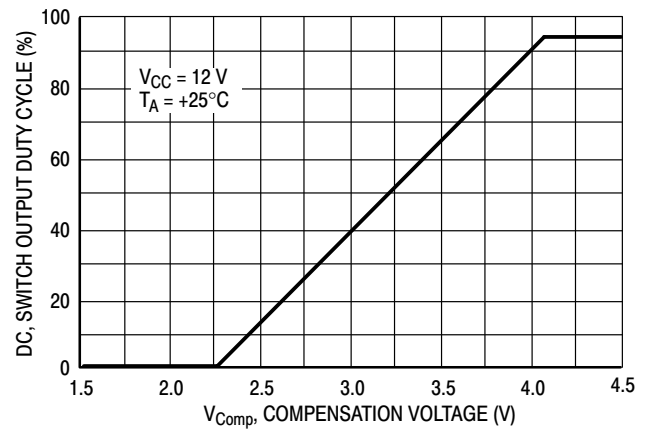


Figure 7. Switch Output Duty Cycle versus Compensation Voltage

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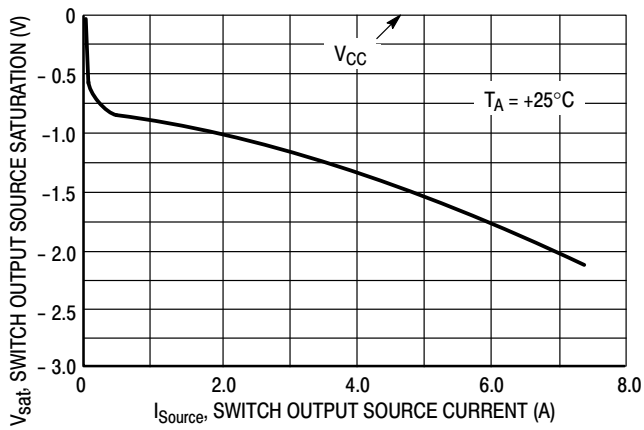


Figure 8. Switch Output Source Saturation versus Source Current

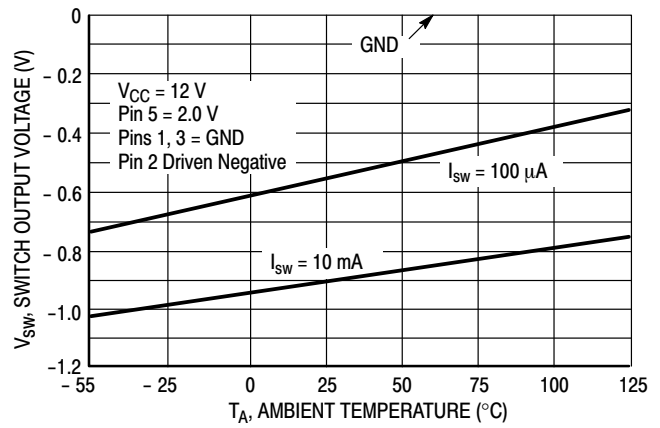


Figure 9. Negative Switch Output Voltage versus Temperature

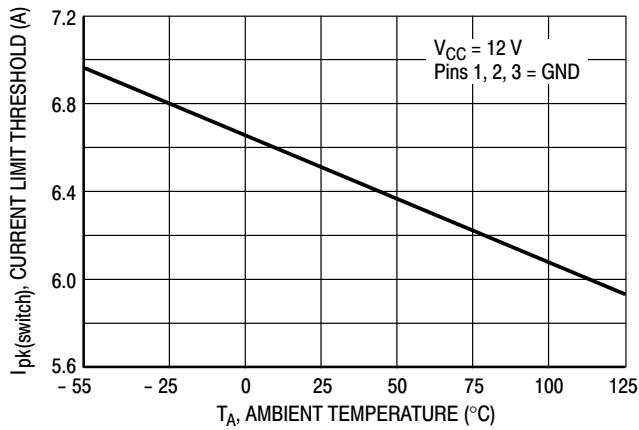


Figure 10. Switch Output Current Limit Threshold versus Temperature

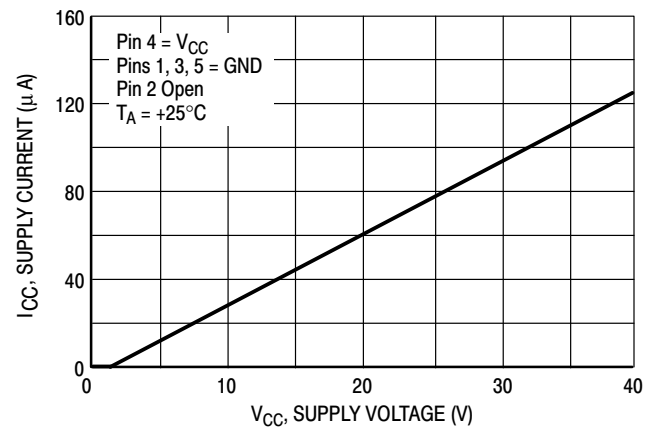


Figure 11. Standby Supply Current versus Supply Voltage

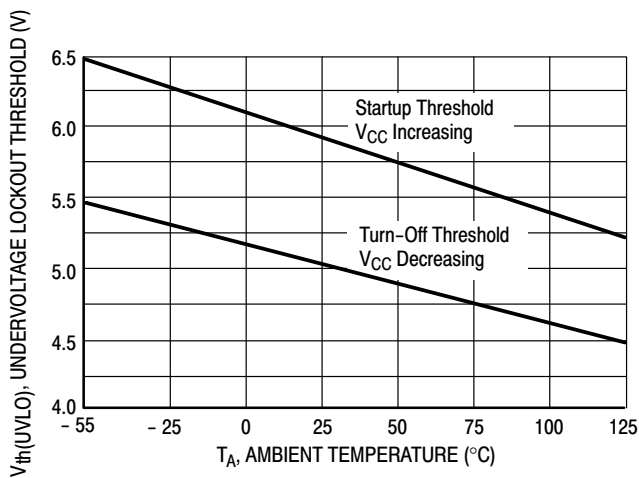


Figure 12. Undervoltage Lockout Thresholds versus Temperature

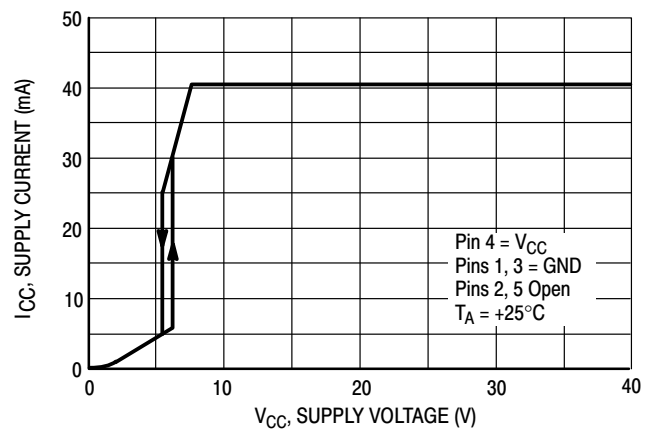


Figure 13. Operating Supply Current versus Supply Voltage

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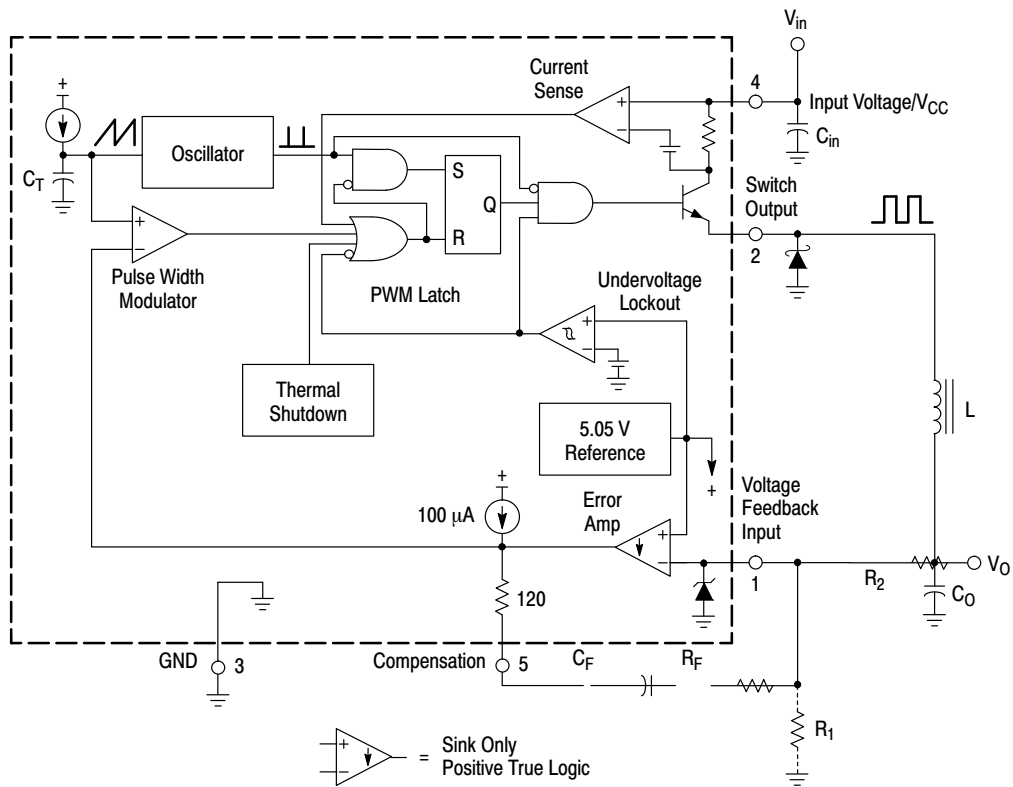


Figure 14. MC34167 Representative Block Diagram

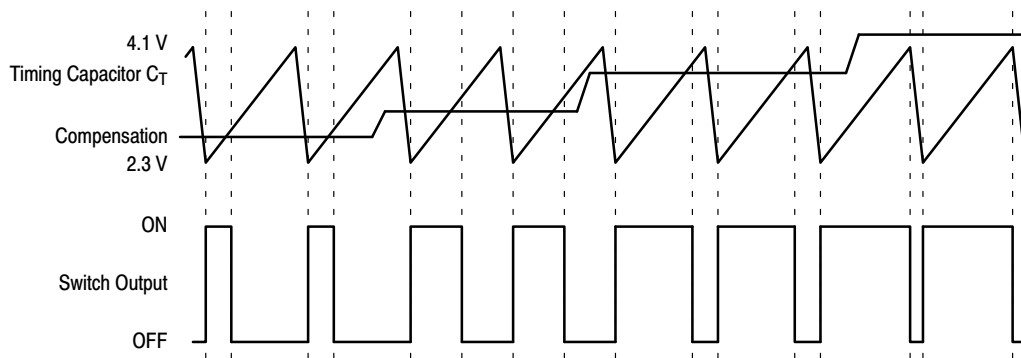


Figure 15. Timing Diagram

INTRODUCTION

The MC34167, MC33167 series are monolithic power switching regulators that are optimized for dc-to-dc converter applications. These devices operate as fixed frequency, voltage mode regulators containing all the active functions required to directly implement step-down and voltage-inverting converters with a minimum number of external components. They can also be used cost effectively in step-up converter applications. Potential markets include automotive, computer, industrial, and cost sensitive consumer products. A description of each section of the device is given below with the representative block diagram shown in Figure 14.

Oscillator

The oscillator frequency is internally programmed to 72 kHz by capacitor C_T and a trimmed current source. The charge to discharge ratio is controlled to yield a 95% maximum duty cycle at the Switch Output. During the discharge of C_T , the oscillator generates an internal blanking pulse that holds the inverting input of the AND gate high, disabling the output switch transistor. The nominal oscillator peak and valley thresholds are 4.1 V and 2.3 V respectively.

Pulse Width Modulator

The Pulse Width Modulator consists of a comparator with the oscillator ramp voltage applied to the noninverting input, while the error amplifier output is applied into the inverting input. Output switch conduction is initiated when C_T is discharged to the oscillator valley voltage. As C_T charges to a voltage that exceeds the error amplifier output, the latch resets, terminating output transistor conduction for the duration of the oscillator ramp-up period. This PWM/Latch combination prevents multiple output pulses during a given oscillator clock cycle. Figures 7 and 15 illustrate the switch output duty cycle versus the compensation voltage.

Current Sense

The MC34167 series utilizes cycle-by-cycle current limiting as a means of protecting the output switch transistor from overstress. Each on cycle is treated as a separate situation. Current limiting is implemented by monitoring the output switch transistor current buildup during conduction, and upon sensing an overcurrent condition, immediately turning off the switch for the duration of the oscillator ramp-up period.

The collector current is converted to a voltage by an internal trimmed resistor and compared against a reference by the Current Sense comparator. When the current limit threshold is reached, the comparator resets the PWM latch. The current limit threshold is typically set at 6.5 A.

Figure 10 illustrates switch output current limit threshold versus temperature.

Error Amplifier and Reference

A high gain Error Amplifier is provided with access to the inverting input and output. This amplifier features a typical dc voltage gain of 80 dB, and a unity gain bandwidth of 600 kHz with 70 degrees of phase margin (Figure 4). The noninverting input is biased to the internal 5.05 V reference and is not pinned out. The reference has an accuracy of $\pm 2.0\%$ at room temperature. To provide 5.0 V at the load, the reference is programmed 50 mV above 5.0 V to compensate for a 1.0% voltage drop in the cable and connector from the converter output. If the converter design requires an output voltage greater than 5.05 V, resistor R_1 must be added to form a divider network at the feedback input as shown in Figures 14 and 19. The equation for determining the output voltage with the divider network is:

$$V_{out} = 5.05 \left(\frac{R_2}{R_1} + 1 \right)$$

External loop compensation is required for converter stability. A simple low-pass filter is formed by connecting a resistor (R_2) from the regulated output to the inverting input, and a series resistor-capacitor (R_F , C_F) between Pins 1 and 5. The compensation network component values shown in each of the applications circuits were selected to provide stability over the tested operating conditions. The step-down converter (Figure 19) is the easiest to compensate for stability. The step-up (Figure 21) and voltage-inverting (Figure 23) configurations operate as continuous conduction flyback converters, and are more difficult to compensate. The simplest way to optimize the compensation network is to observe the response of the output voltage to a step load change, while adjusting R_F and C_F for critical damping. The final circuit should be verified for stability under four boundary conditions. These conditions are minimum and maximum input voltages, with minimum and maximum loads.

By clamping the voltage on the error amplifier output (Pin 5) to less than 150 mV, the internal circuitry will be placed into a low power standby mode, reducing the power supply current to 36 μ A with a 12 V supply voltage. Figure 11 illustrates the standby supply current versus supply voltage.

The Error Amplifier output has a 100 μ A current source pull-up that can be used to implement soft-start. Figure 18 shows the current source charging capacitor C_{SS} through a series diode. The diode disconnects C_{SS} from the feedback loop when the 1.0 M resistor charges it above the operating range of Pin 5.

Switch Output

The output transistor is designed to switch a maximum of 40 V, with a minimum peak collector current of 5.5 A. When configured for step-down or voltage-inverting applications, as in Figures 19 and 23, the inductor will forward bias the output rectifier when the switch turns off. Rectifiers with a high forward voltage drop or long turn on delay time should not be used. If the emitter is allowed to go sufficiently negative, collector current will flow, causing additional device heating and reduced conversion efficiency. Figure 9 shows that by clamping the emitter to 0.5 V, the collector current will be in the range of 100 μ A over temperature. A 1N5825 or equivalent Schottky barrier rectifier is recommended to fulfill these requirements.

Undervoltage Lockout

An Undervoltage Lockout comparator has been incorporated to guarantee that the integrated circuit is fully

functional before the output stage is enabled. The internal reference voltage is monitored by the comparator which enables the output stage when V_{CC} exceeds 5.9 V. To prevent erratic output switching as the threshold is crossed, 0.9 V of hysteresis is provided.

Thermal Protection

Internal Thermal Shutdown circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated, typically at 170°C, the latch is forced into a 'reset' state, disabling the output switch. This feature is provided to prevent catastrophic failures from accidental device overheating. **It is not intended to be used as a substitute for proper heatsinking.** The MC34167 is contained in a 5-lead TO-220 type package. The tab of the package is common with the center pin (Pin 3) and is normally connected to ground.

DESIGN CONSIDERATIONS

Do not attempt to construct a converter on wire-wrap or plug-in prototype boards. Special care should be taken to separate ground paths from signal currents and ground paths from load currents. All high current loops should be kept as short as possible using heavy copper runs to minimize ringing and radiated EMI. For best operation, a

tight component layout is recommended. Capacitors C_{in} , C_O , and all feedback components should be placed as close to the IC as physically possible. It is also imperative that the Schottky diode connected to the Switch Output be located as close to the IC as possible.

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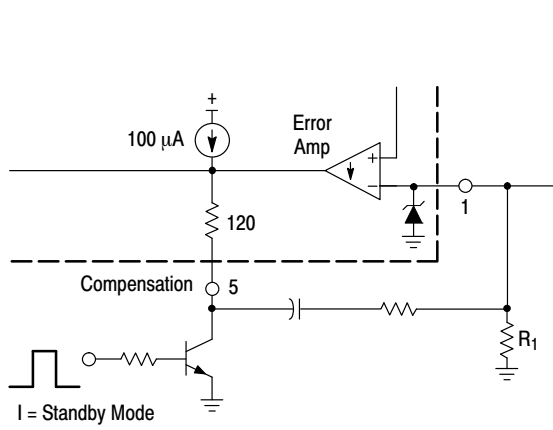


Figure 16. Low Power Standby Circuit

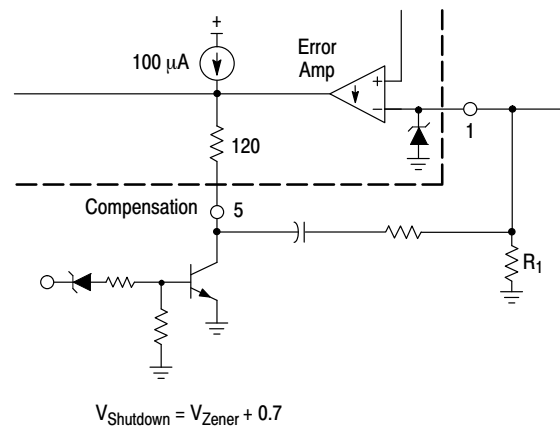


Figure 17. Over Voltage Shutdown Circuit

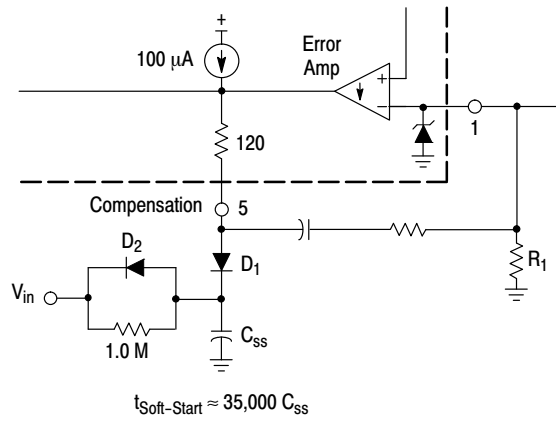
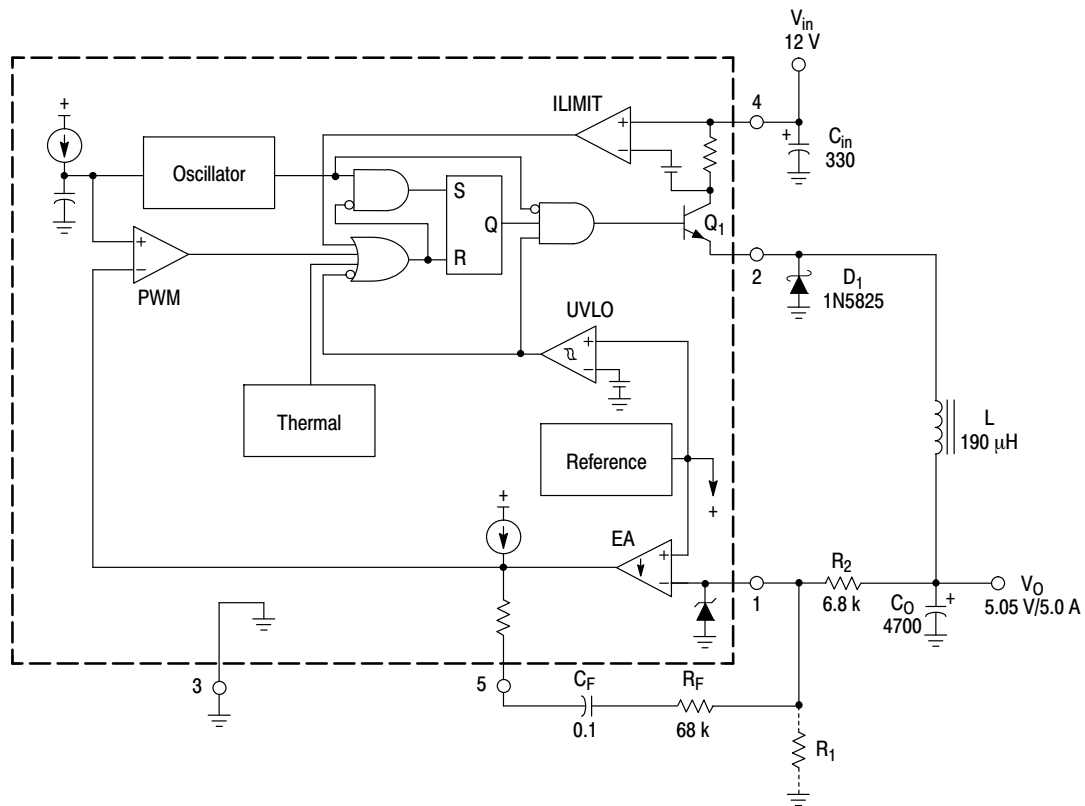


Figure 18. Soft-Start Circuit

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Test	Conditions	Results
Line Regulation	$V_{in} = 10 \text{ V to } 36 \text{ V}$, $I_O = 5.0 \text{ A}$	$4.0 \text{ mV} = \pm 0.039\%$
Load Regulation	$V_{in} = 12 \text{ V}$, $I_O = 0.25 \text{ A to } 5.0 \text{ A}$	$1.0 \text{ mV} = \pm 0.01\%$
Output Ripple	$V_{in} = 12 \text{ V}$, $I_O = 5.0 \text{ A}$	20 mV_{pp}
Short Circuit Current	$V_{in} = 12 \text{ V}$, $R_L = 0.1 \Omega$	6.5 A
Efficiency	$V_{in} = 12 \text{ V}$, $I_O = 5.0 \text{ A}$ $V_{in} = 24 \text{ V}$, $I_O = 5.0 \text{ A}$	78.9% 82.6%

L = Coilcraft M1496-A or General Magnetics Technology GMT-0223, 42 turns of #16 AWG on Magnetics Inc. 58350-A2 core. Heatsink = AAVID Engineering Inc. 5903B, or 5930B.

The Step-Down Converter application is shown in Figure 19. The output switch transistor Q_1 interrupts the input voltage, generating a squarewave at the LC_O filter input. The filter averages the squarewaves, producing a dc output voltage that can be set to any level between V_{in} and V_{ref} by controlling the percent conduction time of Q_1 to that of the total oscillator cycle time. If the converter design requires an output voltage greater than 5.05 V, resistor R_1 must be added to form a divider network at the feedback input.

Figure 19. Step-Down Converter

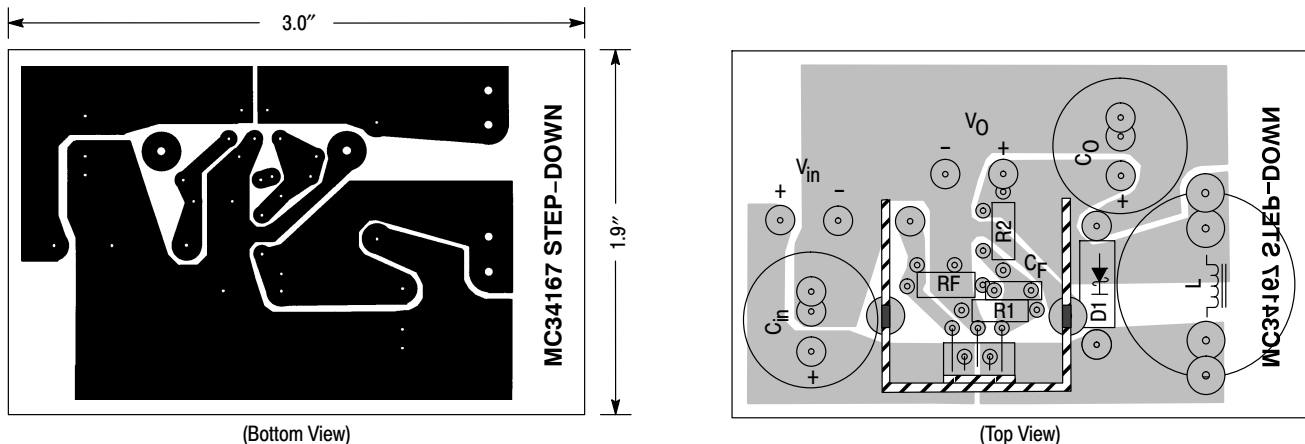
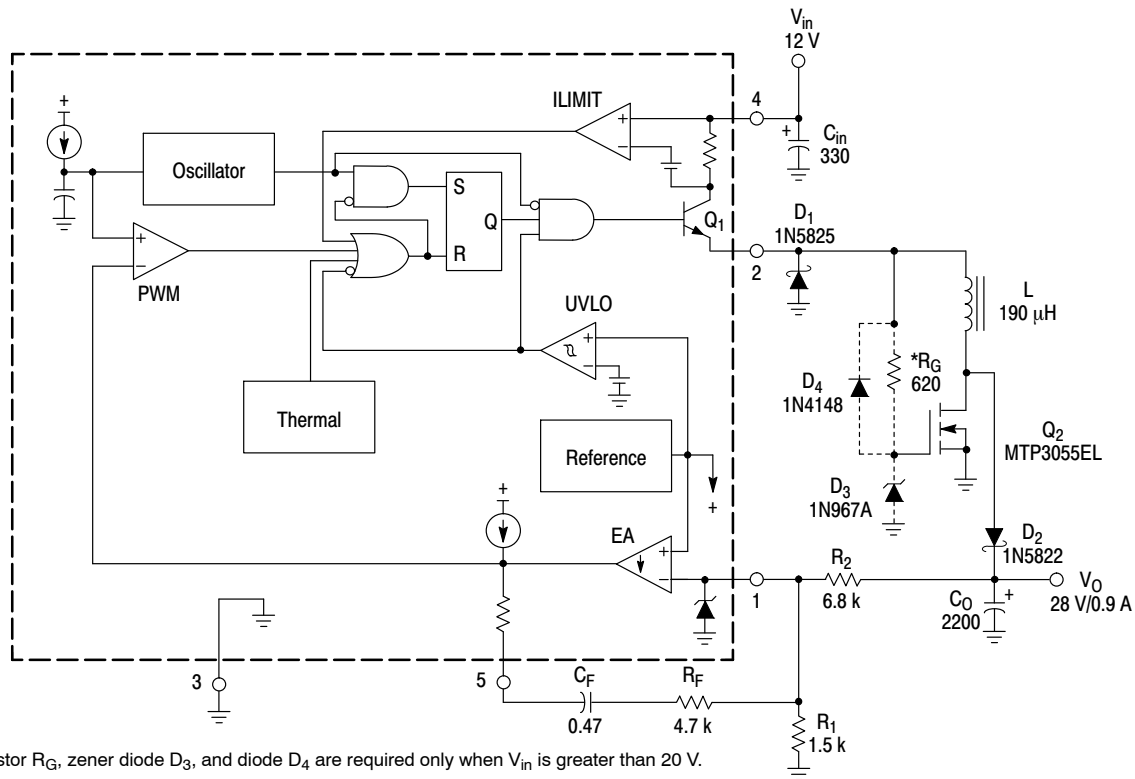


Figure 20. Step-Down Converter Printed Circuit Board and Component Layout

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Test	Conditions	Results
Line Regulation	$V_{in} = 10 \text{ V to } 24 \text{ V}$, $I_O = 0.9 \text{ A}$	$10 \text{ mV} = \pm 0.017\%$
Load Regulation	$V_{in} = 12 \text{ V}$, $I_O = 0.1 \text{ A to } 0.9 \text{ A}$	$30 \text{ mV} = \pm 0.053\%$
Output Ripple	$V_{in} = 12 \text{ V}$, $I_O = 0.9 \text{ A}$	140 mV_{pp}
Short Circuit Current	$V_{in} = 12 \text{ V}$, $R_L = 0.1 \Omega$	6.0 A
Efficiency	$V_{in} = 12 \text{ V}$, $I_O = 0.9 \text{ A}$ $V_{in} = 24 \text{ V}$, $I_O = 0.9 \text{ A}$	80.1% 87.8%

L = Coilcraft M1496-A or General Magnetics Technology GMT-0223, 42 turns of #16 AWG on Magnetics Inc. 58350-A2 core.

Heatsink = Aavid Engineering Inc. MC34167: 5903B, or 5930B MTP3055EL: 5925B

Figure 21 shows that the MC34167 can be configured as a step-up/down converter with the addition of an external power MOSFET. Energy is stored in the inductor during the ON time of transistors Q_1 and Q_2 . During the OFF time, the energy is transferred, with respect to ground, to the output filter capacitor and load. This circuit configuration has two significant advantages over the basic step-up converter circuit. The first advantage is that output short circuit protection is provided by the MC34167, since Q_1 is directly in series with V_{in} and the load. Second, the output voltage can be programmed to be less than V_{in} . Notice that during the OFF time, the inductor forward biases diodes D_1 and D_2 , transferring its energy with respect to ground rather than with respect to V_{in} . When operating with V_{in} greater than 20 V, a gate protection network is required for the MOSFET. The network consists of components R_G , D_3 , and D_4 .

Figure 21. Step-Up/Down Converter

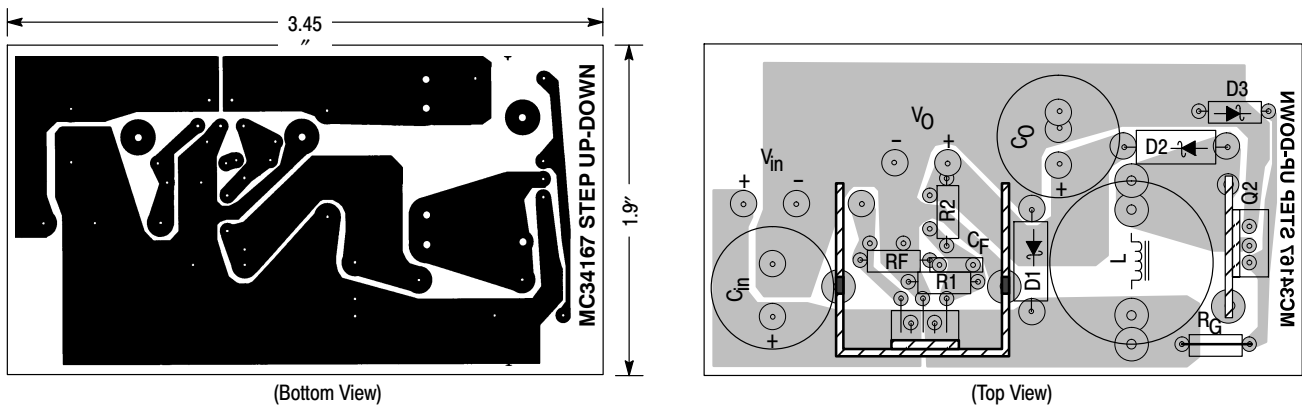
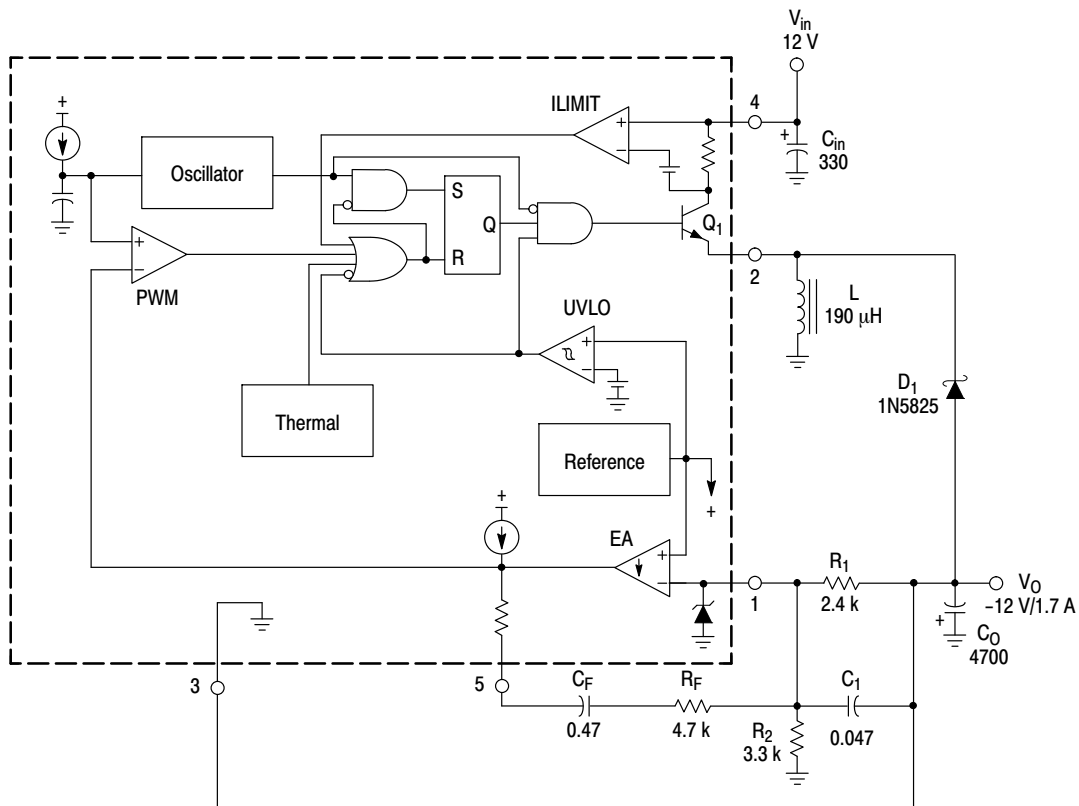


Figure 22. Step-Up/Down Converter Printed Circuit Board and Component Layout

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Test	Conditions	Results
Line Regulation	$V_{in} = 10\text{ V to } 24\text{ V}, I_O = 1.7\text{ A}$	$15\text{ mV} = \pm 0.61\%$
Load Regulation	$V_{in} = 12\text{ V}, I_O = 0.1\text{ A to } 1.7\text{ A}$	$4.0\text{ mV} = \pm 0.020\%$
Output Ripple	$V_{in} = 12\text{ V}, I_O = 1.7\text{ A}$	78 mV_{pp}
Short Circuit Current	$V_{in} = 12\text{ V}, R_L = 0.1\ \Omega$	5.7 A
Efficiency	$V_{in} = 12\text{ V}, I_O = 1.7\text{ A}$	79.5%
	$V_{in} = 24\text{ V}, I_O = 1.7\text{ A}$	86.2%

L = Coilcraft M1496-A or General Magnetics Technology GMT-0223, 42 turns of #16 AWG on Magnetics Inc. 58350-A2 core. Heatsink = Aavid Engineering Inc. 5903B, or 5930B.

Two potential problems arise when designing the standard voltage-inverting converter with the MC34167. First, the Switch Output emitter is limited to -1.5 V with respect to the ground pin and second, the Error Amplifier's noninverting input is internally committed to the reference and is not pinned out. Both of these problems are resolved by connecting the IC ground pin to the converter's negative output as shown in Figure 23. This keeps the emitter of Q_1 positive with respect to the ground pin and has the effect of reversing the Error Amplifier inputs. Note that the voltage drop across R_1 is equal to 5.05 V when the output is in regulation.

Figure 23. Voltage-Inverting Converter

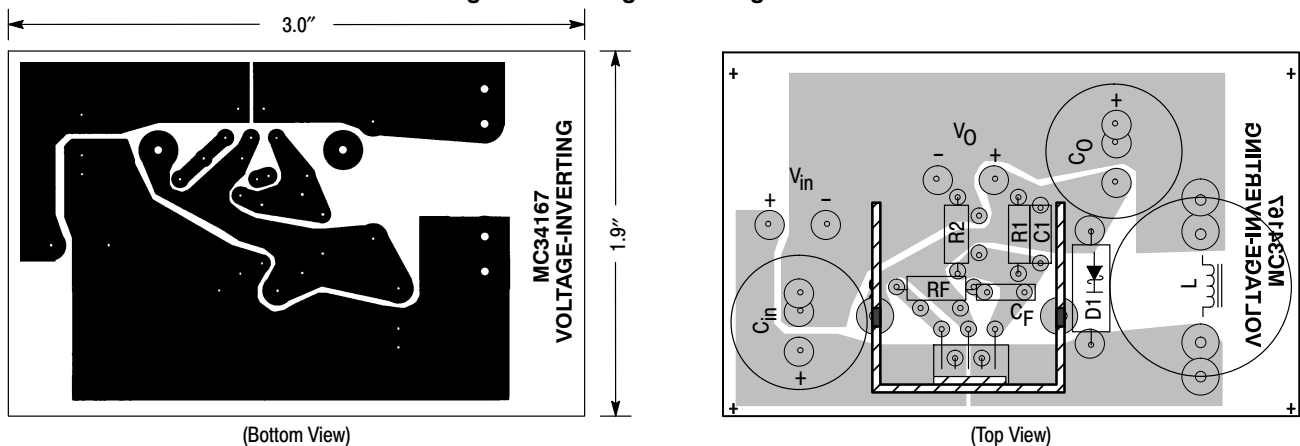


Figure 24. Voltage–Inverting Converter Printed Circuit Board and Component Layout

MC34167, MC33167

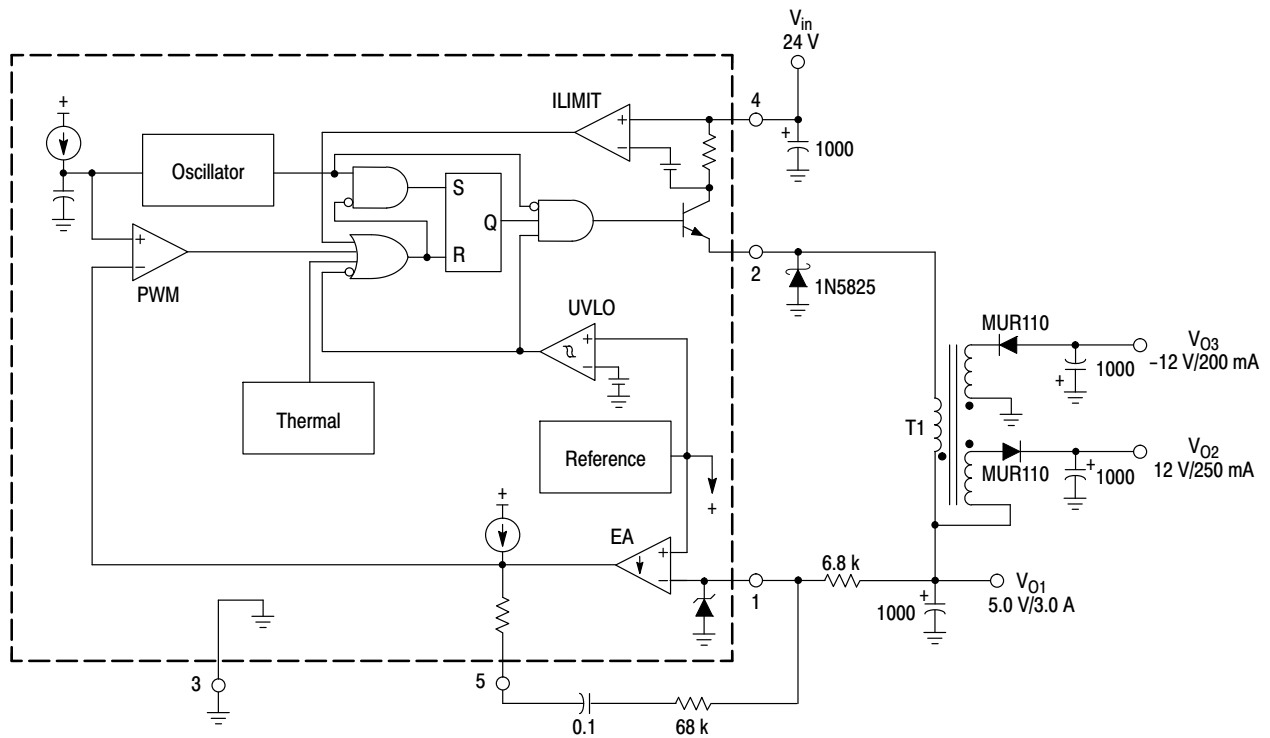


Figure 25. Triple Output Converter

Tests		Conditions	Results
Line Regulation	5.0 V	$V_{in} = 15 \text{ V to } 30 \text{ V}$, $I_{O1} = 3.0 \text{ A}$, $I_{O2} = 250 \text{ mA}$, $I_{O3} = 200 \text{ mA}$	3.0 mV = $\pm 0.029\%$
	12 V		572 mV = $\pm 2.4\%$
	-12 V		711 mV = $\pm 2.9\%$
Load Regulation	5.0 V	$V_{in} = 24 \text{ V}$, $I_{O1} = 30 \text{ mA to } 3.0 \text{ A}$, $I_{O2} = 250 \text{ mA}$, $I_{O3} = 200 \text{ mA}$	1.0 mV = $\pm 0.009\%$
	12 V	$V_{in} = 24 \text{ V}$, $I_{O1} = 3.0 \text{ A}$, $I_{O2} = 100 \text{ mA to } 250 \text{ mA}$, $I_{O3} = 200 \text{ mA}$	409 mV = $\pm 1.5\%$
	-12 V	$V_{in} = 24 \text{ V}$, $I_{O1} = 3.0 \text{ A}$, $I_{O2} = 250 \text{ mA}$, $I_{O3} = 75 \text{ mA to } 200 \text{ mA}$	528 mV = $\pm 2.0\%$
Output Ripple	5.0 V 12 V -12 V	$V_{in} = 24 \text{ V}$, $I_{O1} = 3.0 \text{ A}$, $I_{O2} = 250 \text{ mA}$, $I_{O3} = 200 \text{ mA}$	75 mV _{pp} 20 mV _{pp} 20 mV _{pp}
Short Circuit Current	5.0 V 12 V -12 V	$V_{in} = 24 \text{ V}$, $R_L = 0.1 \Omega$	6.5 A 2.7 A 2.2 A
Efficiency	TOTAL	$V_{in} = 24 \text{ V}$, $I_{O1} = 3.0 \text{ A}$, $I_{O2} = 250 \text{ mA}$, $I_{O3} = 200 \text{ mA}$	84.2%

T1 = Primary: Coilcraft M1496-A or General Magnetics Technology GMT-0223, 42 turns of #16 AWG on Magnetics Inc. 58350-A2 core.

Secondary: V_{O2} - 69 turns of #26 AWG

V_{O3} - 104 turns of #28 AWG

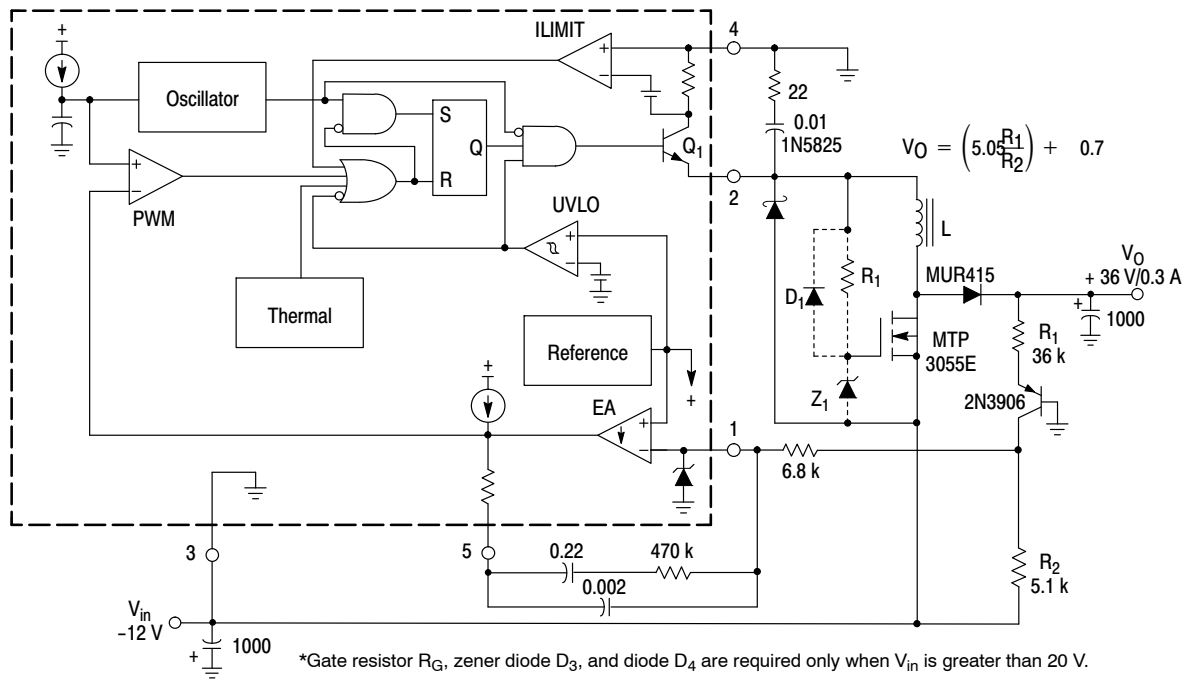
Heatsink = Aavid Engineering Inc. 5903B, or 5930B.

Multiple auxiliary outputs can easily be derived by winding secondaries on the main output inductor to form a transformer. The secondaries must be connected so that the energy is delivered to the auxiliary outputs when the Switch Output turns off. During the OFF time, the voltage across the primary winding is regulated by the feedback loop, yielding a constant Volts/Turn ratio. The number of turns for any given secondary voltage can be calculated by the following equation:

$$\# \text{ TURNS}_{(\text{SEC})} = \frac{V_{O(\text{SEC})} + V_{F(\text{SEC})}}{\left(\frac{V_{O(\text{PRI})} + V_{F(\text{PRI})}}{\# \text{ TURNS}_{(\text{PRI})}} \right)}$$

Note that the 12 V winding is stacked on top of the 5.0 V output. This reduces the number of secondary turns and improves load regulation. For best auxiliary regulation, the auxiliary outputs should be less than 33% of the total output power.

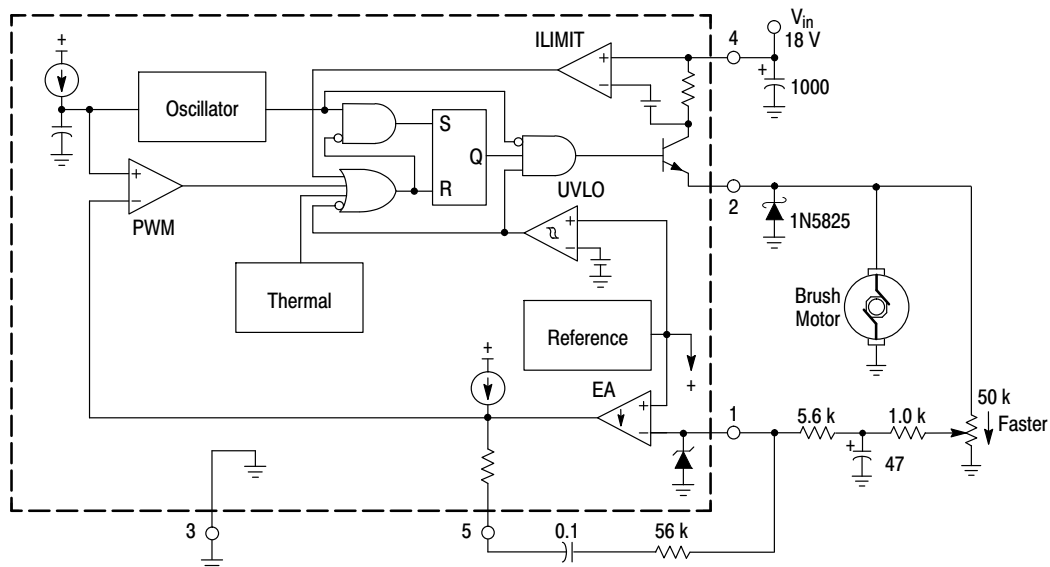
MC34167, MC33167



Test	Conditions	Results
Line Regulation	$V_{in} = -10 \text{ V to } -20 \text{ V}$, $I_O = 0.3 \text{ A}$	266 mV $\pm 0.38\%$
Load Regulation	$V_{in} = -12 \text{ V}$, $I_O = 0.03 \text{ A to } 0.3 \text{ A}$	7.90 mV $\pm 1.1\%$
Output Ripple	$V_{in} = -12 \text{ V}$, $I_O = 0.3 \text{ A}$	100 mV _{pp}
Efficiency	$V_{in} = -12 \text{ V}$, $I_O = 0.3 \text{ A}$	78.4%

L = General Magnetics Technology GMT-0223, 42 turns of #16 AWG on Magnetics Inc. 58350-A2 core. Heatsink = Aavid Engineering Inc. 5903B or 5930B

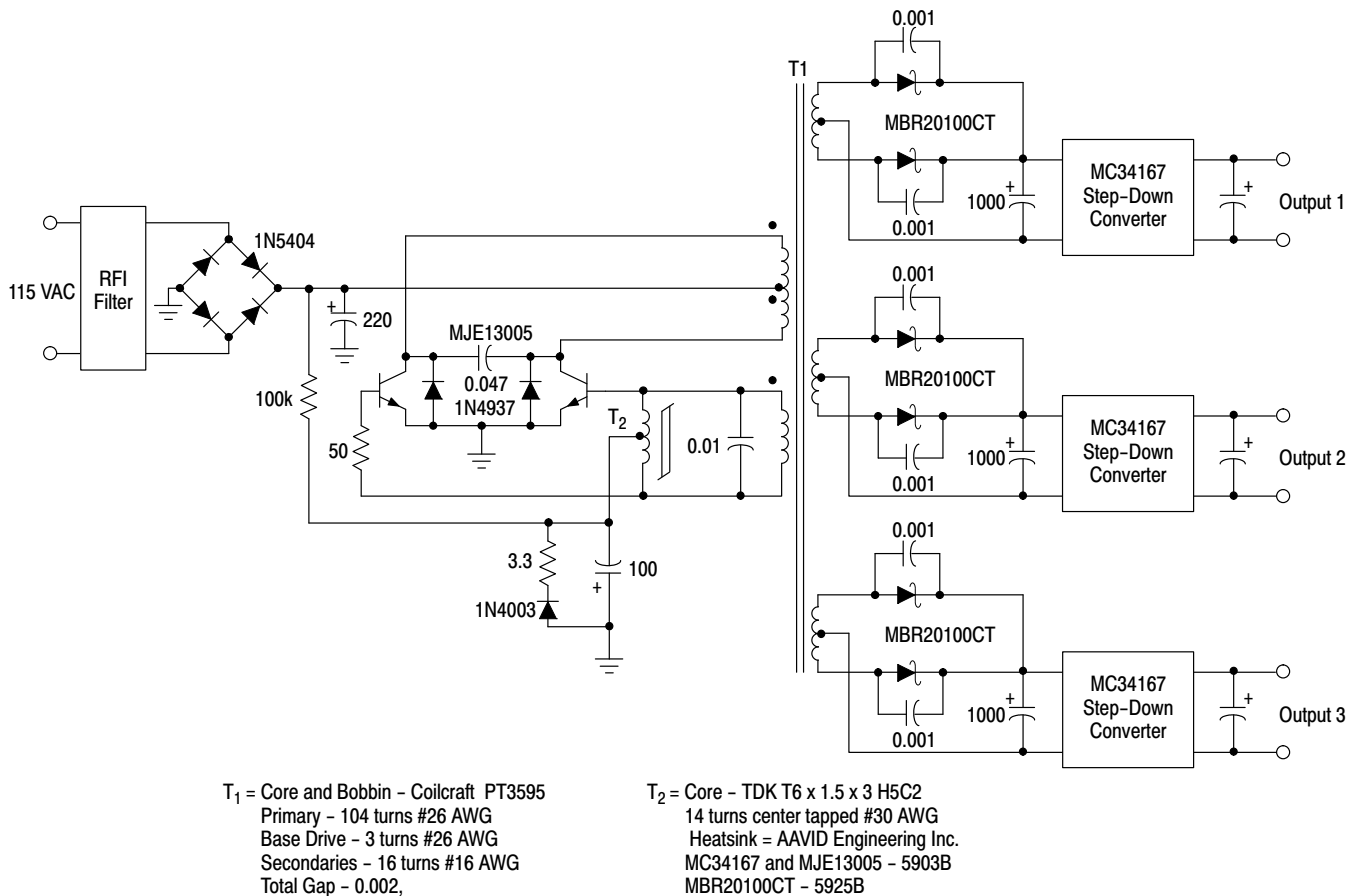
Figure 26. Negative Input/Positive Output Regulator



Test	Conditions	Results
Low Speed Line Regulation	$V_{in} = 12 \text{ V to } 24 \text{ V}$	1760 RPM $\pm 1\%$
High Speed Line Regulation	$V_{in} = 12 \text{ V to } 24 \text{ V}$	3260 RPM $\pm 6\%$

Figure 27. Variable Motor Speed Control with EMF Feedback Sensing

MC34167, MC33167



The MC34167 can be used cost effectively in off-line applications even though it is limited to a maximum input voltage of 40 V. Figure 28 shows a simple and efficient method for converting the AC line voltage down to 24 V. This preconverter has a total power rating of 125 W with a conversion efficiency of 90%. Transformer T_1 provides output isolation from the AC line and isolation between each of the secondaries. The circuit self-oscillates at 50 kHz and is controlled by the saturation characteristics of T_2 . Multiple MC34167 post regulators can be used to provide accurate independently regulated outputs for a distributed power system.

Figure 28. Off-Line Preconverter

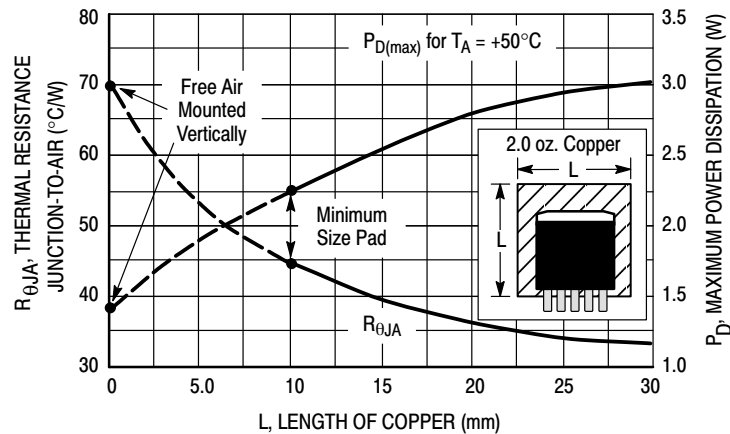


Figure 29. D²PAK Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

MC34167, MC33167

Table 1. Design Equations

Calculation	Step-Down	Step-Up/Down	Voltage-Inverting
$\frac{t_{on}}{t_{off}}$ (Notes 1, 2)	$\frac{V_{out} + V_F}{V_{in} - V_{sat} - V_{out}}$	$\frac{V_{out} + V_{F1} + V_{F2}}{V_{in} - V_{satQ1} - V_{satQ2}}$	$\frac{ V_{out} + V_F}{V_{in} - V_{sat}}$
t_{on}	$\frac{\frac{t_{on}}{t_{off}}}{f_{osc} \left(\frac{t_{on}}{t_{off}} + 1 \right)}$	$\frac{\frac{t_{on}}{t_{off}}}{f_{osc} \left(\frac{t_{on}}{t_{off}} + 1 \right)}$	$\frac{\frac{t_{on}}{t_{off}}}{f_{osc} \left(\frac{t_{on}}{t_{off}} + 1 \right)}$
Duty Cycle (Note 3)	$t_{on} f_{osc}$	$t_{on} f_{osc}$	$t_{on} f_{osc}$
$I_{L \text{ avg}}$	I_{out}	$I_{out} \left(\frac{t_{on}}{t_{off}} + 1 \right)$	$I_{out} \left(\frac{t_{on}}{t_{off}} + 1 \right)$
$I_{pk(switch)}$	$I_{L \text{ avg}} + \frac{\Delta I_L}{2}$	$I_{L \text{ avg}} + \frac{\Delta I_L}{2}$	$I_{L \text{ avg}} + \frac{\Delta I_L}{2}$
L	$\left(\frac{V_{in} - V_{sat} - V_{out}}{\Delta I_L} \right) t_{on}$	$\left(\frac{V_{in} - V_{satQ1} - V_{satQ2}}{\Delta I_L} \right) t_{on}$	$\left(\frac{V_{in} - V_{sat}}{\Delta I_L} \right) t_{on}$
$V_{ripple(pp)}$	$\Delta I_L \sqrt{\left(\frac{1}{8f_{osc}C_O} \right)^2 + (ESR)^2}$	$\left(\frac{t_{on}}{t_{off}} + 1 \right) \sqrt{\left(\frac{1}{f_{osc}C_O} \right)^2 + (ESR)^2}$	$\left(\frac{t_{on}}{t_{off}} + 1 \right) \sqrt{\left(\frac{1}{f_{osc}C_O} \right)^2 + (ESR)^2}$
V_{out}	$V_{ref} \left(\frac{R_2}{R_1} + 1 \right)$	$V_{ref} \left(\frac{R_2}{R_1} + 1 \right)$	$V_{ref} \left(\frac{R_2}{R_1} + 1 \right)$

1. V_{sat} – Switch Output source saturation voltage, refer to Figure 8.
2. V_F – Output rectifier forward voltage drop. Typical value for 1N5822 Schottky barrier rectifier is 0.35 V.
3. Duty cycle is calculated at the minimum operating input voltage and must not exceed the guaranteed minimum $DC_{(max)}$ specification of 0.92.

The following converter characteristics must be chosen:

- V_{out} – Desired output voltage.
- I_{out} – Desired output current.
- ΔI_L – Desired peak-to-peak inductor ripple current. For maximum output current especially when the duty cycle is greater than 0.5, it is suggested that ΔI_L be chosen minimum current limit threshold of 5.5 A. If the design goal is to use a minimum inductance value, let $\Delta I_L = 2 (I_{L \text{ avg}})$. This will proportionally reduce the converter's output current capability.
- $V_{ripple(pp)}$ – Desired peak-to-peak output ripple voltage. For best performance, the ripple voltage should be kept to less than 2% of V_{out} . Capacitor C_O should be a low equivalent series resistance (ESR) electrolytic designed for switching regulator applications.

MC34167, MC33167

ORDERING INFORMATION

Device	Operating Temperature Range	Package	Shipping [†]
MC33167D2T	T _A = -40° to +85°C	D ² PAK (Surface Mount)	50 Units / Rail
MC33167D2TG		D ² PAK (Surface Mount) (Pb-Free)	50 Units / Rail
MC33167D2TR4		D ² PAK (Surface Mount)	800 / Tape & Reel
MC33167D2TR4G		D ² PAK (Surface Mount) (Pb-Free)	800 / Tape & Reel
MC33167T		TO-220 (Straight Lead)	50 Units / Rail
MC33167TG		TO-220 (Straight Lead) (Pb-Free)	50 Units / Rail
MC33167TH		TO-220 (Horizontal Mount)	50 Units / Rail
MC33167THG		TO-220 (Horizontal Mount) (Pb-Free)	50 Units / Rail
MC33167TV		TO-220 (Vertical Mount)	50 Units / Rail
MC33167TVG		TO-220 (Vertical Mount) (Pb-Free)	50 Units / Rail
MC34167D2T	T _A = 0° to +70°C	D ² PAK (Surface Mount)	50 Units / Rail
MC34167D2TG		D ² PAK (Surface Mount) (Pb-Free)	50 Units / Rail
MC34167D2TR4		D ² PAK (Surface Mount)	800 / Tape & Reel
MC34167D2TR4G		D ² PAK (Surface Mount) (Pb-Free)	800 / Tape & Reel
MC34167T		TO-220 (Straight Lead)	50 Units / Rail
MC34167TG		TO-220 (Straight Lead) (Pb-Free)	50 Units / Rail
MC34167TH		TO-220 (Horizontal Mount)	50 Units / Rail
MC34167THG		TO-220 (Horizontal Mount) (Pb-Free)	50 Units / Rail
MC34167TV		TO-220 (Vertical Mount)	50 Units / Rail
MC34167TVG		TO-220 (Vertical Mount) (Pb-Free)	50 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MECHANICAL CASE OUTLINE

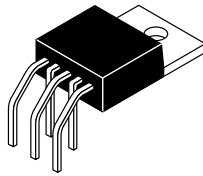
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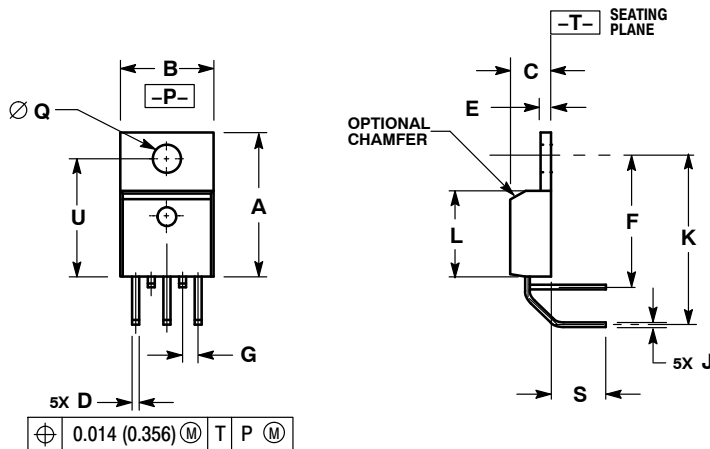


5 LEAD TO-220 (THA5) CASE 314A-03 ISSUE E

DATE 09/29/2000



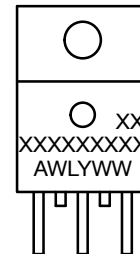
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NOTES:

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2. CONTROLLING DIMENSION: INCH.
3. DIMENSION D DOES NOT INCLUDE INTERCONNECT BAR (DAMBAR) PROTRUSION. DIMENSION D INCLUDING PROTRUSION SHALL NOT EXCEED 0.043 (1.092) MAXIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.572	0.613	14.529	15.570
B	0.390	0.415	9.906	10.541
C	0.170	0.180	4.318	4.572
D	0.025	0.038	0.635	0.965
E	0.048	0.055	1.219	1.397
F	0.570	0.585	14.478	14.859
G	0.067	BSC	1.702	BSC
J	0.015	0.025	0.381	0.635
K	0.730	0.745	18.542	18.923
L	0.320	0.365	8.128	9.271
Q	0.140	0.153	3.556	3.886
S	0.210	0.260	5.334	6.604
U	0.468	0.505	11.888	12.827



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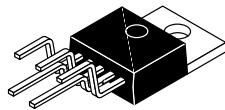
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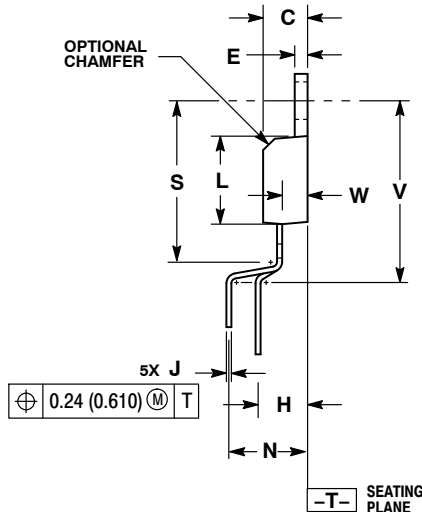
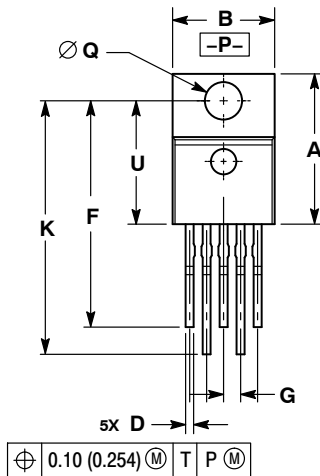
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	MIN	MAX	MIN	MAX
A	0.572	0.613	14.529	15.570
B	0.390	0.415	9.906	10.541
C	0.170	0.180	4.318	4.572
D	0.025	0.038	0.635	0.965
E	0.048	0.055	1.219	1.397
F	0.850	0.935	21.590	23.749
G	0.067 BSC		1.702 BSC	
H	0.166 BSC		4.216 BSC	
J	0.015	0.025	0.381	0.635
K	0.900	1.100	22.860	27.940
L	0.320	0.365	8.128	9.271
N	0.320 BSC		8.128 BSC	
Q	0.140	0.153	3.556	3.886
S	---	0.620	---	15.748
U	0.468	0.505	11.888	12.827
V	---	0.735	---	18.669
W	0.090	0.110	2.286	2.794

STYLE 1 THRU 4:
CANCELLED

STYLE 5:
PIN 1. GATE
2. MIRROR
3. DRAIN
4. KELVIN
5. SOURCE

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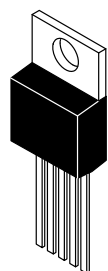
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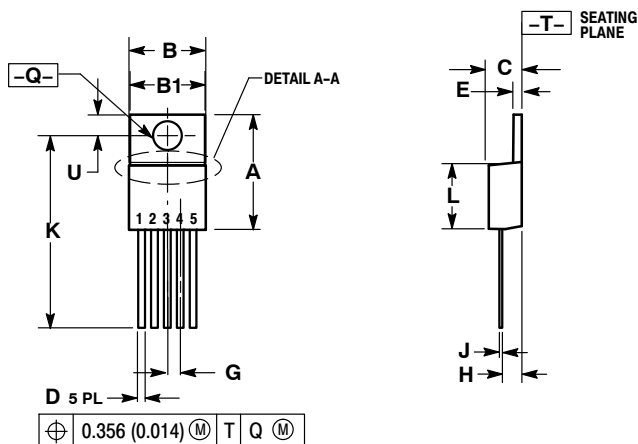


TO-220 5-LEAD CASE 314D-04 ISSUE H

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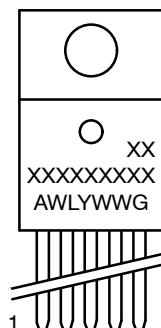
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	MIN	MAX	MIN	MAX
A	0.572	0.613	14.529	15.570
B	0.390	0.415	9.906	10.541
B1	0.375	0.415	9.525	10.541
C	0.170	0.180	4.318	4.572
D	0.025	0.038	0.635	0.965
E	0.048	0.055	1.219	1.397
G	0.067 BSC		1.702 BSC	
H	0.087	0.112	2.210	2.845
J	0.015	0.025	0.381	0.635
K	0.977	1.045	24.810	26.543
L	0.320	0.365	8.128	9.271
Q	0.140	0.153	3.556	3.886
U	0.105	0.117	2.667	2.972

STYLE 1 THRU 4:

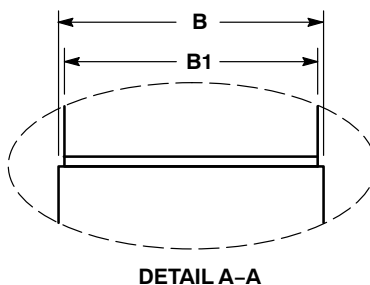
1. OBSOLETE

GENERIC MARKING DIAGRAM*



A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.



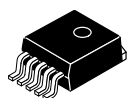
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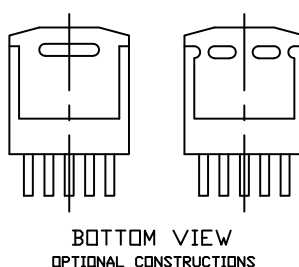
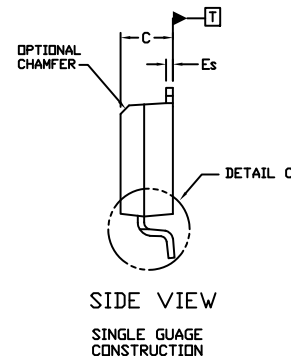
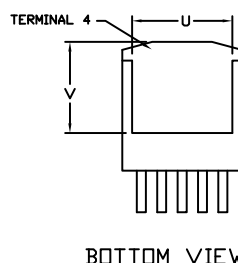
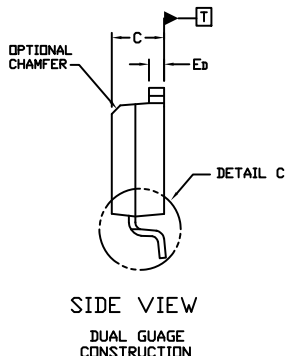
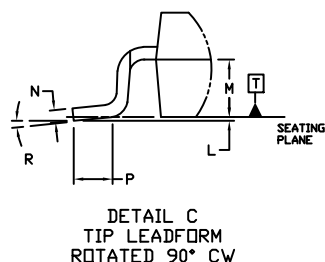
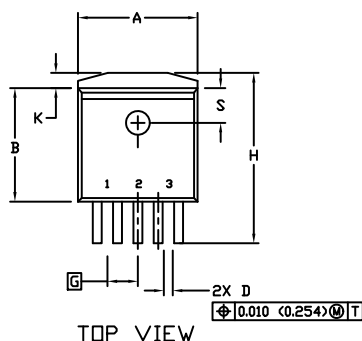
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D²PAK 5-LEAD CASE 936A-02 ISSUE E

DATE 28 JUL 2021

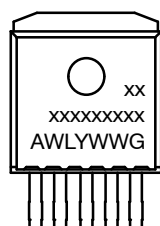
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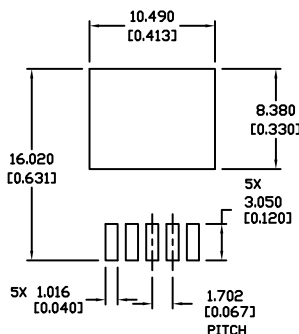
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2. CONTROLLING DIMENSION: INCHES
3. TAB CONTOUR OPTIONAL WITHIN DIMENSIONS A AND K.
4. DIMENSIONS U AND V ESTABLISH A MINIMUM MOUNTING SURFACE FOR TERMINAL 4.
5. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.025 (0.635) MAXIMUM.

GENERIC MARKING DIAGRAM*



xxxxxx = Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DIM	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.396	0.403	9.804	10.236
B	0.356	0.368	9.042	9.347
C	0.170	0.180	4.318	4.572
D	0.026	0.036	0.660	0.914
Ed	0.045	0.055	1.143	1.397
Es	0.018	0.026	0.457	0.660
G	0.067	BSC	1.702	BSC
H	0.539	0.579	13.691	14.707
K	0.050	REF	1.270	REF
L	0.000	0.010	0.000	0.254
M	0.088	0.102	2.235	2.591
N	0.018	0.026	0.457	0.660
P	0.058	0.078	1.473	1.981
R	0°	8°	0°	8°
S	0.116	REF	2.946	REF
U	0.200	MIN	5.080	MIN
V	0.250	MIN	6.350	MIN

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